

# **PMN70EPE** 30 V, P-channel Trench MOSFET

23 May 2017

**Product data sheet** 

## 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

## 2. Features and benefits

- Trench MOSFET technology
- Logic-level compatible
- Very fast switching
- Enhanced power dissipation capability of 1.4 W
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

## 3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

## 4. Quick reference data

Table 1. Quid	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-30	V
V <sub>GS</sub>	gate-source voltage			-20	-	20	V
I <sub>D</sub>	drain current	$V_{GS}$ = -10 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	-	-4.4	А
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = -10 V; I <sub>D</sub> = -3.3 A; T <sub>j</sub> = 25 °C		-	60	80	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



# 5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	D	drain		D			
2	D	drain					
3	G	gate		G ↓ ↓ ↓ ↓			
4	S	source	TSOP6 (SOT457)				
5	D	drain					
6	D	drain		s S			
				017aaa259			

# 6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMN70EPE	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457				

# 7. Marking

Table 4. Marking codes	
Type number	Marking code
PMN70EPE	G2

## 8. Limiting values

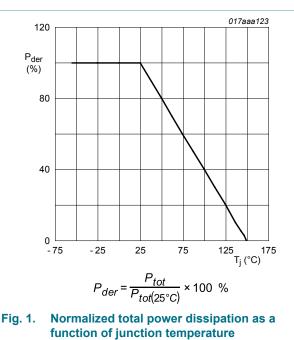
### Table 5. Limiting values

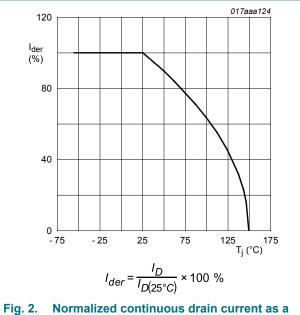
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-30	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-4.4	А
		V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 25 °C	[1]	-	-3.3	А
		V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 100 °C	[1]	-	-2.1	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-14	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	570	mW
			[1]	-	1.4	W
		T <sub>sp</sub> = 25 °C		-	6.25	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode		·			
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-1.4	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

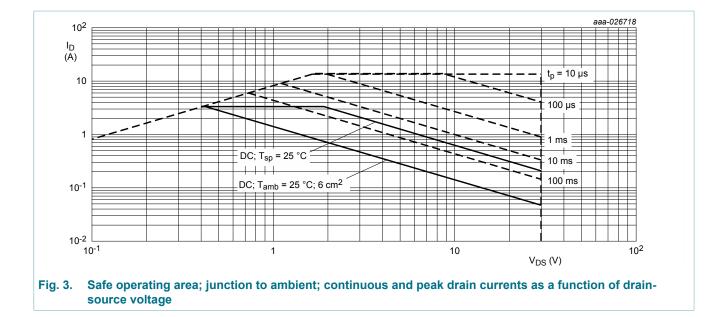




function of junction temperature

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## 9. Thermal characteristics

### Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	-	[1]	-	190	220	K/W
			[2]	-	78	90	K/W
		in free air; t ≤ 5 s	[2]	-	47	54	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	15	20	K/W

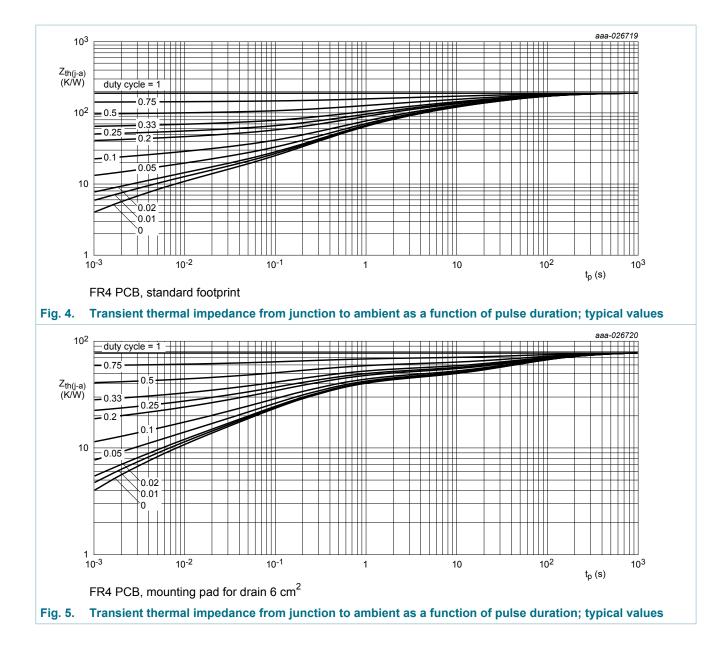
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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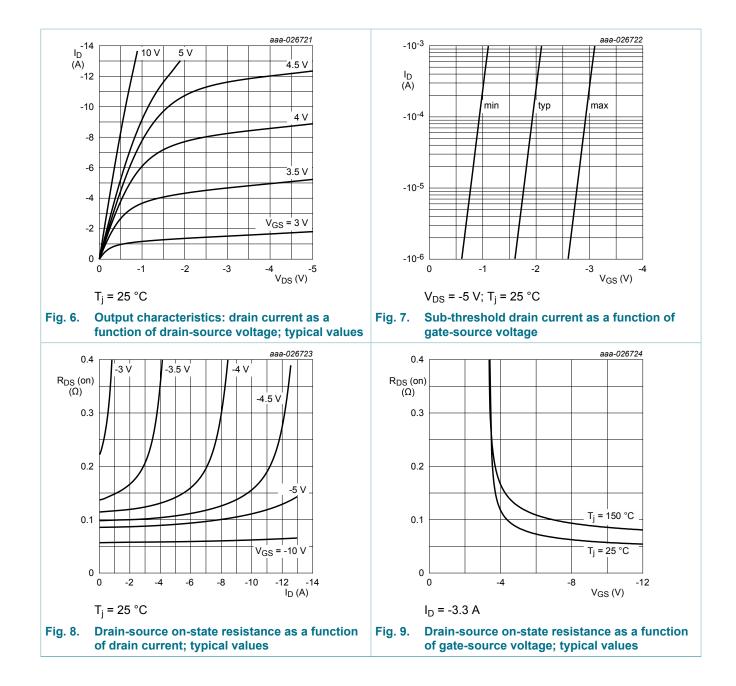
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## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-30	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-1	-2	-3	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = -30 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		$V_{GS}$ = -20 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-10	μA
		V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
		$V_{GS}$ = -10 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
		$V_{GS}$ = 4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	100	nA
		$V_{GS}$ = -4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-100	nA
Boon	drain-source on-state	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -3.3 A; T <sub>j</sub> = 25 °C	-	60	80	mΩ
	resistance	V <sub>GS</sub> = -10 V; I <sub>D</sub> = -3.3 A; T <sub>j</sub> = 150 °C	-	91	121	mΩ
		V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -2.6 A; T <sub>j</sub> = 25 °C	-	96	140	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = -10 V; I <sub>D</sub> = -2 A; T <sub>j</sub> = 25 °C	-	12.6	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C	-	12	-	Ω
Dynamic ch	aracteristics					
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -15 V; $I_D$ = -3.3 A; $V_{GS}$ = -10 V;	-	6.5	11.5	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1.2	-	nC
Q <sub>GD</sub>	gate-drain charge		-	1.2	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = -15 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	370	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	64	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	44	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -15 V; $I_{D}$ = -3.3 A; $V_{GS}$ = -10 V;	-	5	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	8	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	19	-	ns
t <sub>f</sub>	fall time		-	7.5	-	ns
Source-drai	n diode			1	1	
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -1.4 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.8	-1.2	V

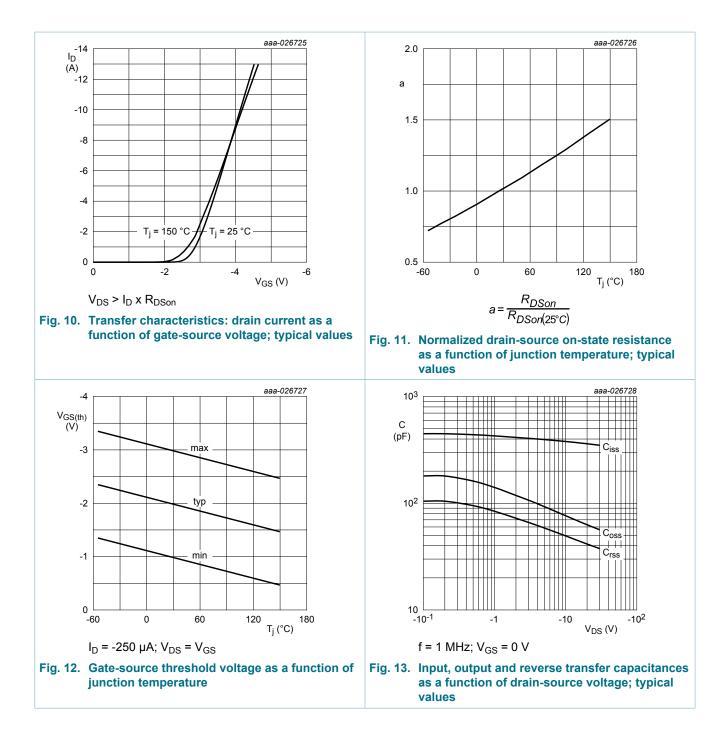
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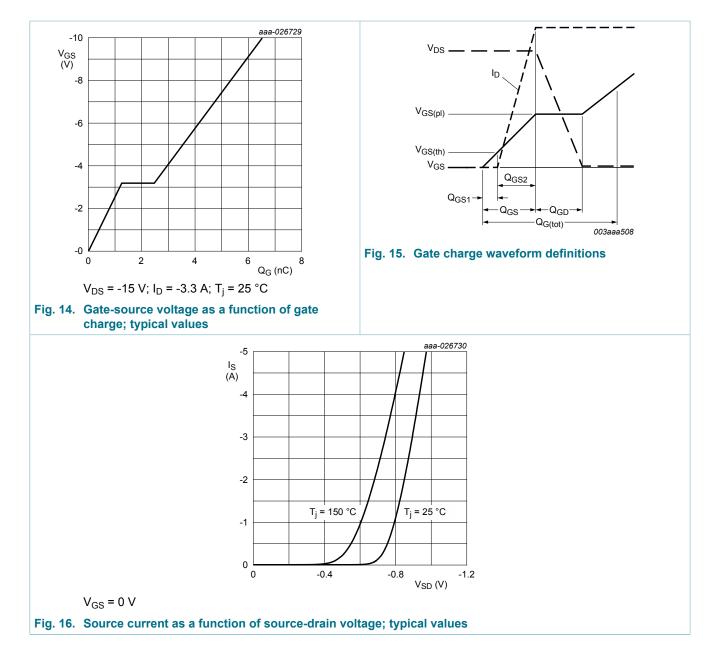


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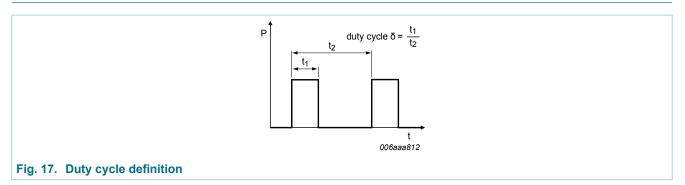
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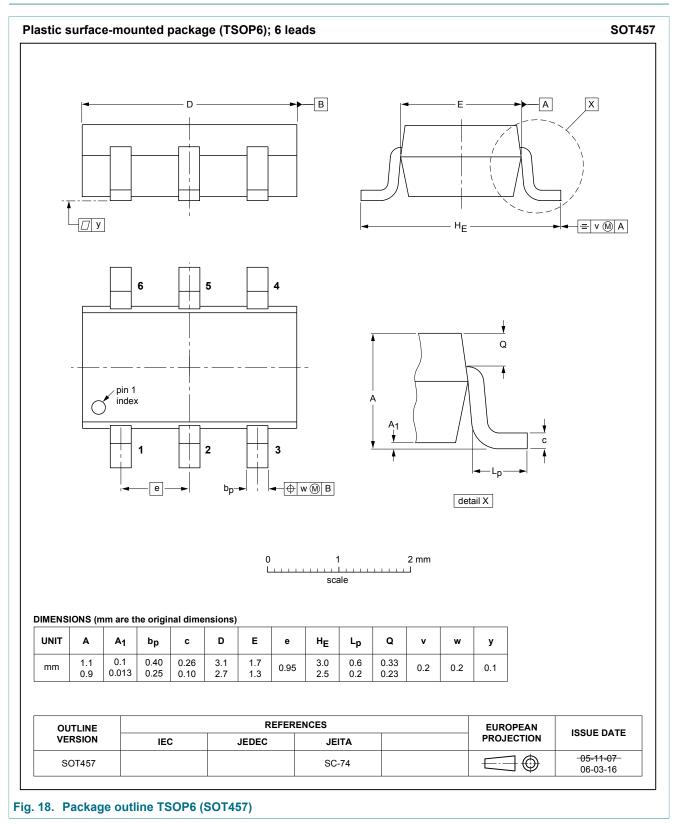
## **11. Test information**



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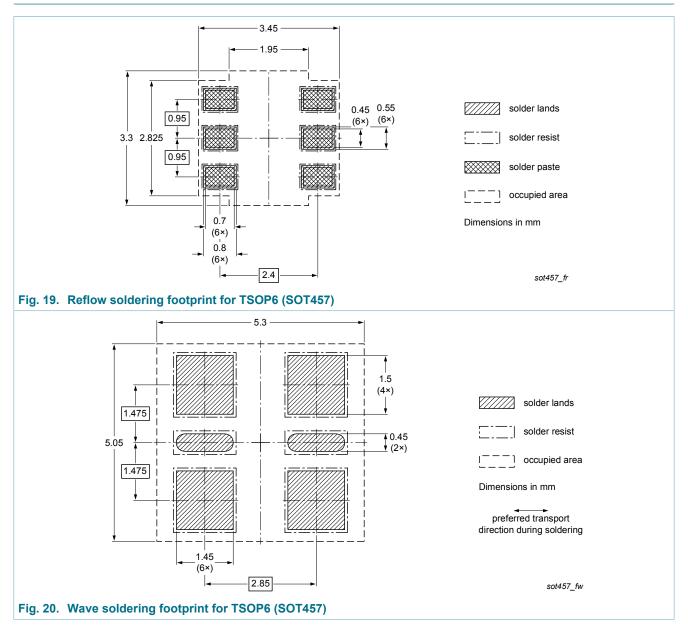
## 12. Package outline



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## 13. Soldering



# 14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMN70EPE v.1	20170523	Product data sheet	-	-			

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## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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